

SuperMOS – SOT-523 60V BV_{DSS} , 1.85Ω $R_{DS(on)}$, N-channel MOSFET

1. Description

The NTA7002NT1G-ES is N-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(on)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product NTA7002NT1G-ES is Pb-free.

2. Features

- 60V, $R_{DS(on)}=1.85\Omega$ (TYP.) @ $V_{GS}=10V$
 $R_{DS(on)}=2.05\Omega$ (TYP.) @ $V_{GS}=4.5V$
- High density cell design for low $R_{DS(on)}$
- ESD Protection - HBM: 2kV
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
NTA7002NT1G-ES	SOT-523	72KW	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

5. Pin Configuration and Functions

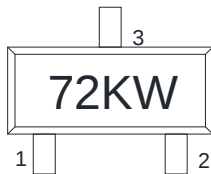
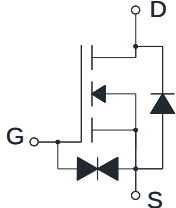
Pin	Function	Outline	Circuit Diagram
1	Gate		
2	Source		
3	Drain		

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	60	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	$T_A=25^{\circ}\text{C}$	I_D	0.3	A
	$T_A=100^{\circ}\text{C}$		0.2	
Maximum Power Dissipation		P_D	350	mW
Pulsed Drain Current		I_{DM}	1.2	A
Operating Junction Temperature		T_J	150	°C
Lead Temperature		T_L	260	°C
Storage Temperature Range		T_{stg}	-55 to 150	°C

Thermal resistance ratings

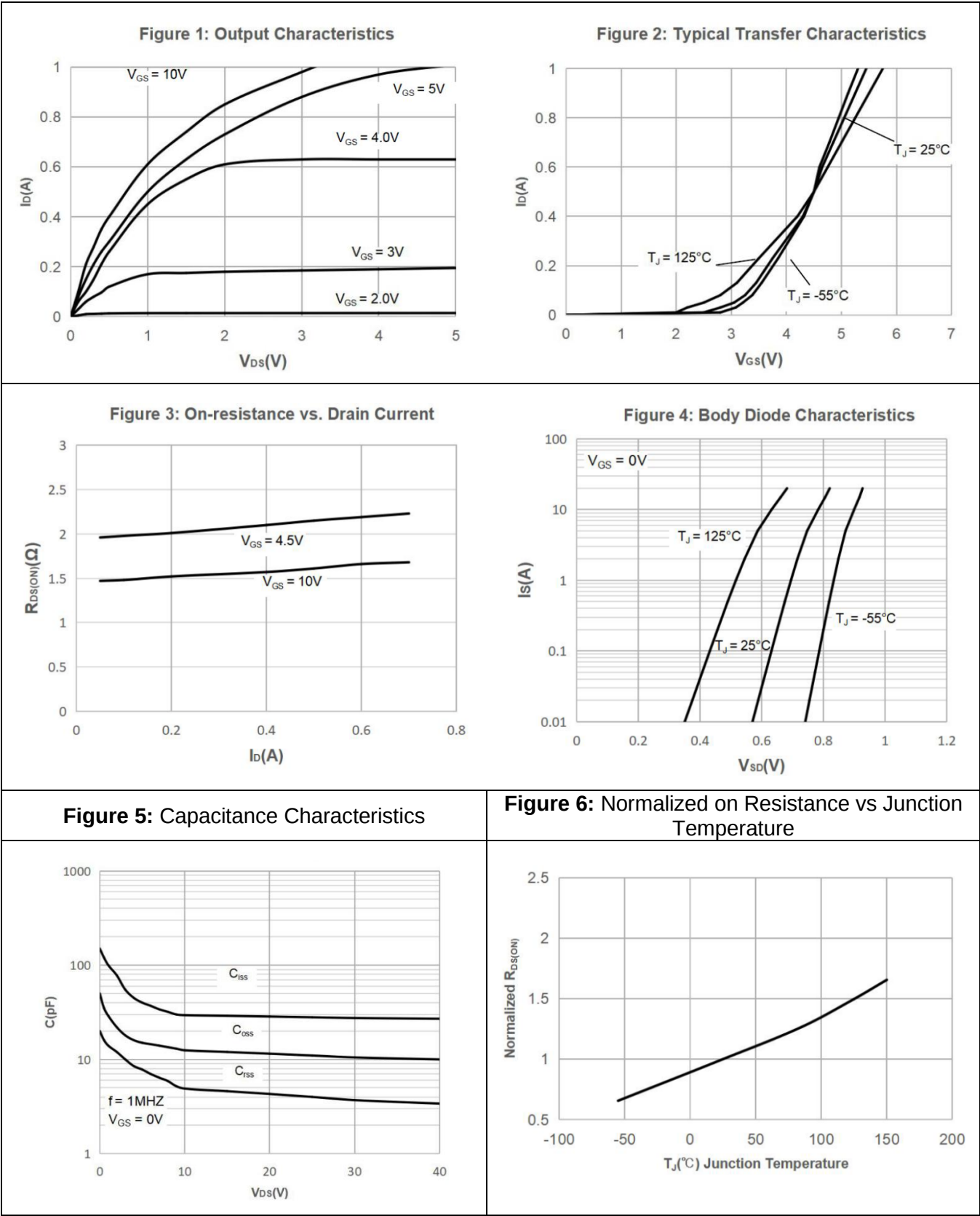
Single Operation			
Parameter	Symbol	Typical	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	357	°C/W

Electrical Characteristics

At TA = 25°C unless otherwise specified

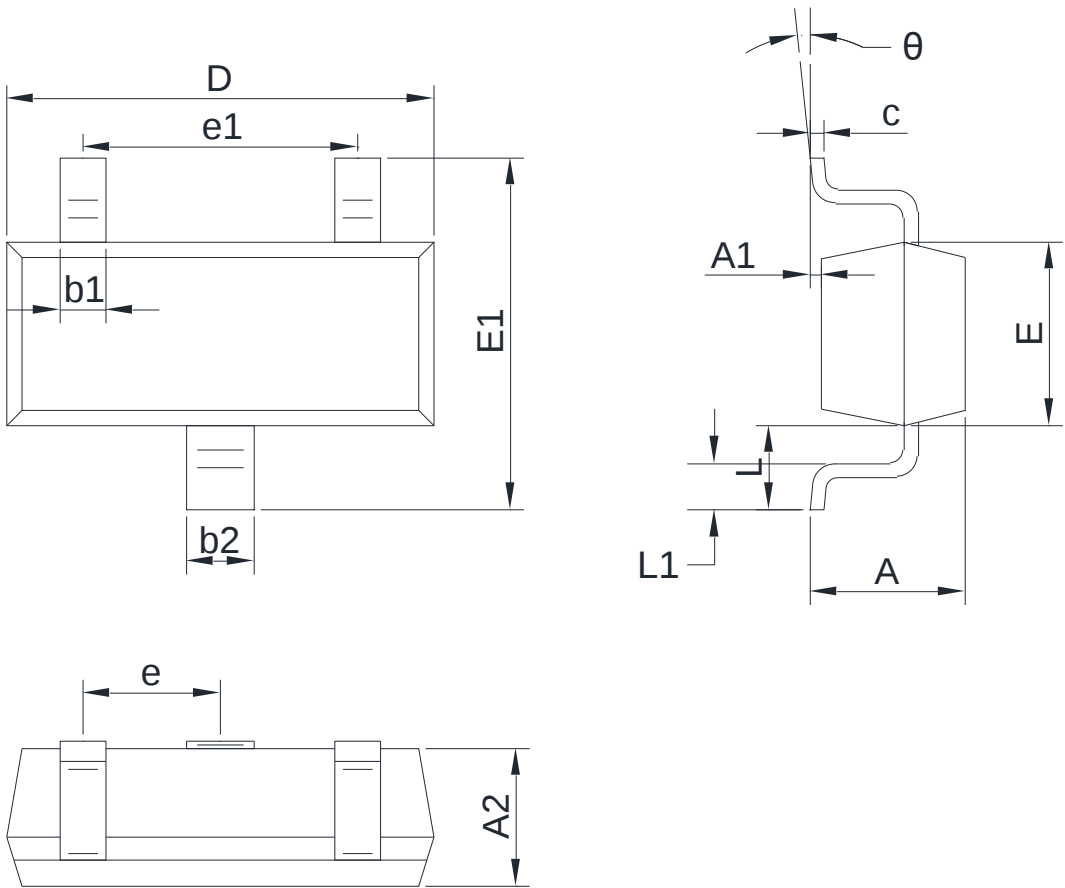
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1.0	uA
Gate-to-source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±10	uA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =250uA	1.0	1.6	2.5	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =10V, I _D =0.3A		1.85	2.2	Ω
		V _{GS} =4.5V, I _D =0.2A		2.05	3.0	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, f=1MHz, V _{DS} =25V		28		pF
Output Capacitance	C _{OSS}			11		
Reverse Transfer Capacitance	C _{RSS}			4		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =4.5V, V _{DS} =10V, I _D =0.3A		1.8		nC
Gate-to-Source Charge	Q _{GS}			0.3		
Gate-to-Drain Charge	Q _{GD}			0.6		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =10V, V _{DS} =10V, I _D =0.2A, R _G =10Ω		2		ns
Rise Time	t _r			15		
Turn-Off Delay Time	t _{d(OFF)}			7		
Fall Time	t _f			20		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _S =0.3A			1.5	V

7. Typical Characteristic



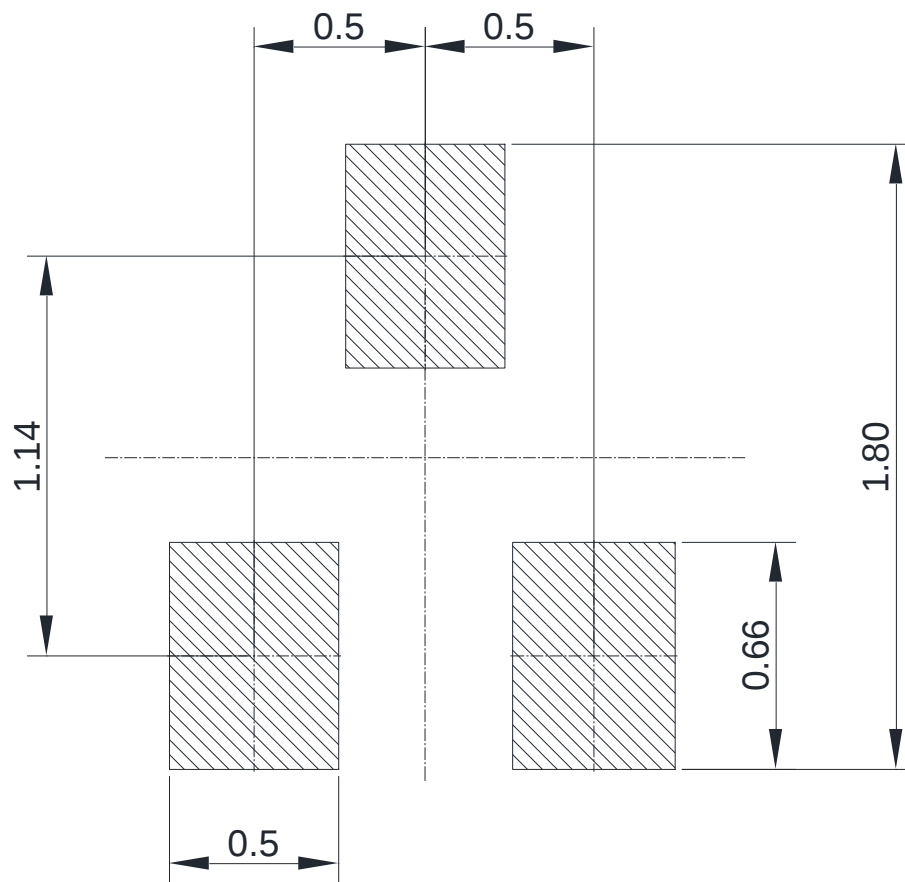
8. Dimension (SOT-523)

POD(Z)



REF	Millimeters		REF	Millimeters	
	Min	Max		Min	Max
A	0.70	0.90	E1	1.45	1.75
A1	0.00	0.10	E	0.70	0.90
A2	0.70	0.80	e	0.50TYP	
b1	0.15	0.25	e1	0.90	1.10
b2	0.25	0.35	L	0.40REF	
c	0.10	0.20	L1	0.25	0.46
D	1.50	1.70	θ	0°	8°

9. Recommended Soldering Footprint



DIMENSIONS: MILLIMETERS

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